

# HiPerFRED

$V_{RRM}$  = 300 V  
 $I_{FAV}$  = 60 A  
 $t_{rr}$  = 35 ns

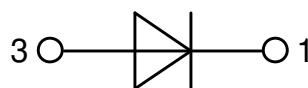
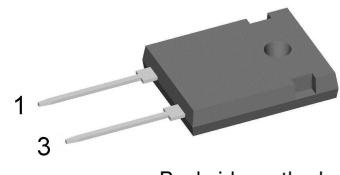
High Performance Fast Recovery Diode

Low Loss and Soft Recovery

Single Diode

Part number

**DPG60I300HA**



## Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low  $I_{rm}$ -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low  $I_{rm}$  reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

## Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

## Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

## Disclaimer Notice

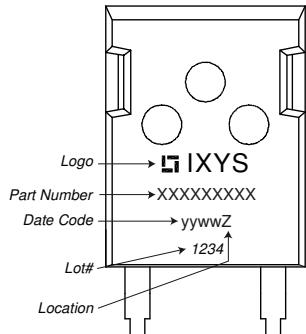
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**Fast Diode**

Symbol	Definition	Conditions	Ratings				
			min.	typ.	max.		
$V_{RSM}$	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			300	V	
$V_{RRM}$	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			300	V	
$I_R$	reverse current, drain current	$V_R = 300 \text{ V}$ $V_R = 300 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 150^\circ\text{C}$		1 0.35	$\mu\text{A}$ mA	
$V_F$	forward voltage drop	$I_F = 60 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$		1.40	V	
		$I_F = 120 \text{ A}$			1.72	V	
		$I_F = 60 \text{ A}$	$T_{VJ} = 150^\circ\text{C}$		1.10	V	
		$I_F = 120 \text{ A}$			1.45	V	
$I_{FAV}$	average forward current	$T_C = 130^\circ\text{C}$ rectangular	$T_{VJ} = 175^\circ\text{C}$		60	A	
$V_{F0}$	threshold voltage	$T_{VJ} = 175^\circ\text{C}$			0.69	V	
$r_F$	slope resistance } for power loss calculation only				5.8	$\text{m}\Omega$	
$R_{thJC}$	thermal resistance junction to case				0.55	K/W	
$R_{thCH}$	thermal resistance case to heatsink			0.3		K/W	
$P_{tot}$	total power dissipation	$T_C = 25^\circ\text{C}$			275	W	
$I_{FSM}$	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}; V_R = 0 \text{ V}$	$T_{VJ} = 45^\circ\text{C}$		550	A	
$C_J$	junction capacitance	$V_R = 150 \text{ V}$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$	80		pF	
$I_{RM}$	max. reverse recovery current	$I_F = 60 \text{ A}; V_R = 150 \text{ V}$ $-di_F/dt = 200 \text{ A}/\mu\text{s}$	$T_{VJ} = 25^\circ\text{C}$	3.5		A	
$t_{rr}$	reverse recovery time		$T_{VJ} = 125^\circ\text{C}$	9		A	
			$T_{VJ} = 25^\circ\text{C}$	35		ns	
			$T_{VJ} = 125^\circ\text{C}$	65		ns	

**Package TO-247**

Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal			70	A
$T_{VJ}$	virtual junction temperature		-55		175	°C
$T_{op}$	operation temperature		-55		150	°C
$T_{stg}$	storage temperature		-55		150	°C
<b>Weight</b>				6		g
$M_d$	mounting torque		0.8		1.2	Nm
$F_c$	mounting force with clip		20		120	N

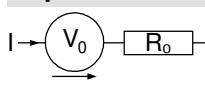
**Product Marking**

**Part description**

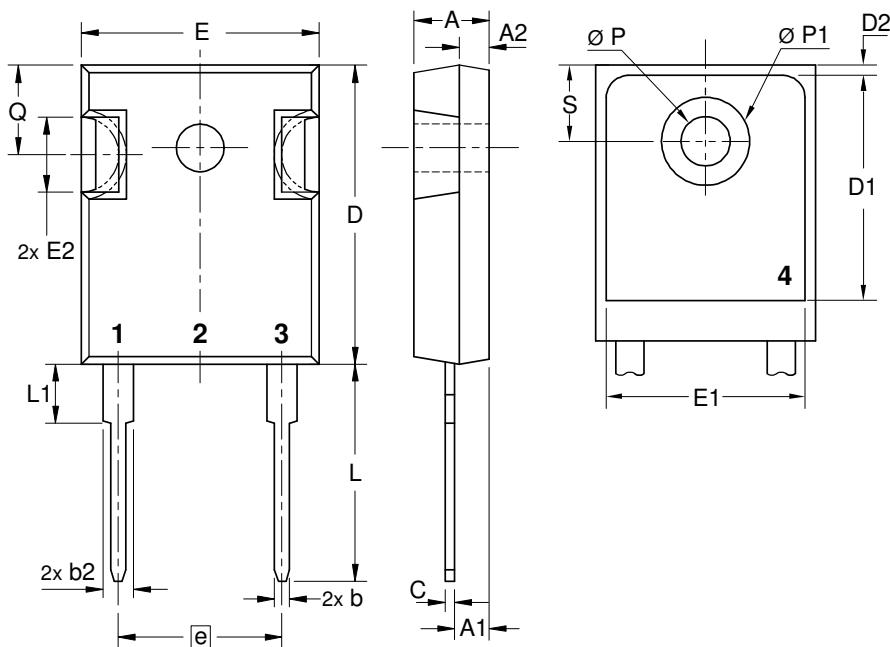
D = Diode  
P = HiPerFRED  
G = extreme fast  
60 = Current Rating [A]  
I = Single Diode  
300 = Reverse Voltage [V]  
HA = TO-247AD (2)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DPG60I300HA	DPG60I300HA	Tube	30	585818

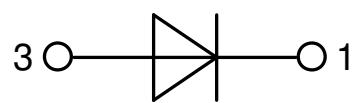
Similar Part	Package	Voltage class
DPG60IM300PC	TO-263AB (D2Pak) (2)	300

**Equivalent Circuits for Simulation**
*\* on die level*
 $T_{VJ} = 175^\circ\text{C}$ 

	<b>Fast Diode</b>	
$V_{0\ max}$	threshold voltage	0.69 V
$R_{0\ max}$	slope resistance *	3.2 mΩ

**Outlines TO-247**


Sym.	Inches min. max.	Millimeter min. max.
A	0.185 0.209	4.70 5.30
A1	0.087 0.102	2.21 2.59
A2	0.059 0.098	1.50 2.49
D	0.819 0.845	20.79 21.45
E	0.610 0.640	15.48 16.24
E2	0.170 0.216	4.31 5.48
e	0.430 BSC	10.92 BSC
L	0.780 0.800	19.80 20.30
L1	- 0.177	- 4.49
Ø P	0.140 0.144	3.55 3.65
Q	0.212 0.244	5.38 6.19
S	0.242 BSC	6.14 BSC
b	0.039 0.055	0.99 1.40
b2	0.065 0.094	1.65 2.39
b4	0.102 0.135	2.59 3.43
c	0.015 0.035	0.38 0.89
D1	0.515 -	13.07 -
D2	0.020 0.053	0.51 1.35
E1	0.530 -	13.45 -
Ø P1	- 0.29	- 7.39



### Fast Diode

